SOT-227 Power Module
Single Switch - Power MOSFET, 400 A

SOT-227

FEATURES

- I_D = 400 A, T_C = 25 °C
- ThunderFET Power MOSFET
- Excellent gate charge x $R_{DS(on)}$ product (FOM)
- Reduced switching and conduction losses
- Ultra low gate charge (Q_g)
- Maximum 175 °C junction temperature
- UL approved file E78996
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Pb-free

RoHS COMPLIANT

PRIMARY CHARACTERISTICS	
V_{DSS}	150 V
$R_{DS(on)}$ at 200 A	1.93 mΩ
I_D	300 A at 90 °C
Type	Modules - MOSFET
Package	SOT-227

APPLICATIONS

- DC/DC conversions
- Motor drives
- DC/AC inverter
- Power supplies
- Uninterruptible power supplies
- AC/DC switch-mode power supplies

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MAX.**	**UNITS**
MOSFET				
Drain to source voltage	V_{DSS}		150	V
Continuous drain current, $V_{GS\ at}$ 10 V	I_D	T_C = 25 °C	400	A
		T_C = 90 °C	300	
Pulsed drain current	I_{DM} (1)		860	
Power dissipation	P_D	T_C = 25 °C	909	W
Gate to source voltage	V_{GS}		± 20	V
Single pulse avalanche current	E_{AS}		720	J
Avalanche current	I_{AS}	T_C = 25 °C, L = 10 mH, V_{GS} = 10 V	120	A
MODULE				
Operating junction temperature range	T_J		-55 to +175	°C
Operating storage temperature range	T_{Stg}		-40 to +150	
Insulation voltage (RMS)	V_{ISOL}	any terminal to case, t = 1 min	2500	V

Note

(1) Limited at max. junction temperature

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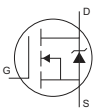
THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Operating junction temperature range		T_J		-55	-	175	°C
Operating storage temperature range		T_{Stg}		-40	-	150	
Junction to case	MOSFET	R_{thJC}		-	-	0.165	°C/W
Case to heatsink	Module	R_{thCS}	Flat, greased surface	-	0.1	-	
Weight				-	30	-	g
Mounting torque			Torque to terminal	-	-	1.1 (9.7)	Nm (lbf. in)
			Torque to heatsink	-	-	1.3 (11.5)	Nm (lbf. in)
Case style				SOT-227			

ELECTRICAL CHARACTERISTICS (T_J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Drain to source breakdown voltage	$V_{(BR)DSS}$	V_{GS} = 0 V, I_D = 500 µA	150	-	-	V
Breakdown voltage temperature coefficient	$\Delta V_{(BR)DSS}/\Delta T_J$	Reference to 25 °C, I_D = 1.0 mA	-	9.0	-	mV/°C
Static drain to source on-resistance	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 200 A	-	1.93	2.75	mΩ
Gate threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 1.0 mA	1.80	3.46	5.4	V
Temperature coefficient of threshold voltage	$\Delta V_{GE(th)}/\Delta T_J$	V_{DS} = V_{GS}, I_D = 1.0 mA (25 °C to 125 °C)	-	9.6	-	mV/°C
Forward transconductance	g_{fs}	V_{DS} = 15 V, I_D = 100 A, V_{GS} = 10 V	-	200	-	S
Drain to source leakage current	I_{DSS}	V_{DS} = 150 V, V_{GS} = 0 V	-	0.5	10.0	µA
		V_{DS} = 150 V, V_{GS} = 0 V, T_J = 150 °C	-	19	-	
Gate to source leakage	I_{GSS}	V_{GS} = ± 20 V	-	-	± 200	nA
Total gate charge	Q_g	I_D = 250 A V_{DS} = 75 V V_{GS} = 10 V	-	250	-	nC
Gate to source charge	Q_{gs}		-	79	-	
Gate to drain ("Miller") charge	Q_{gd}		-	82	-	
Turn-on delay time	$t_{d(on)}$	V_{DD} = 75 V I_D = 100 A R_g = 1 Ω V_{GS} = 10 V	-	139	-	ns
Rise time	t_r		-	285	-	
Turn-off delay time	$t_{d(off)}$		-	120	-	
Fall time	t_f		-	142	-	
Input capacitance	C_{iss}	V_{GS} = 0 V V_{DS} = 25 V f = 1 MHz	-	13.7	-	nF
Output capacitance	C_{oss}		-	2.2	-	
Reverse transfer capacitance	C_{rss}		-	0.104	-	

SOURCE-DRAIN RATINGS AND CHARACTERISTICS (T_J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Continuous source current (body diode)	I_S	MOSFET symbol showing the integral reverse p-n junction diode 	-	-	476	A
Pulsed source current (body diode)	I_{SM}		-	-	850	
Diode forward voltage	V_{SD}	I_S = 250 A, V_{GS} = 0 V	-	0.95	-	V
Reverse recovery time	t_{rr}	T_J = 25 °C, I_F = I_S = 50 A, dI/dt = 100 A/µs, V_R = 50 V	-	171	-	ns
Reverse recovery charge	Q_{rr}		-	1032	-	nC
Reverse recovery current	I_{RM}		-	12	-	A

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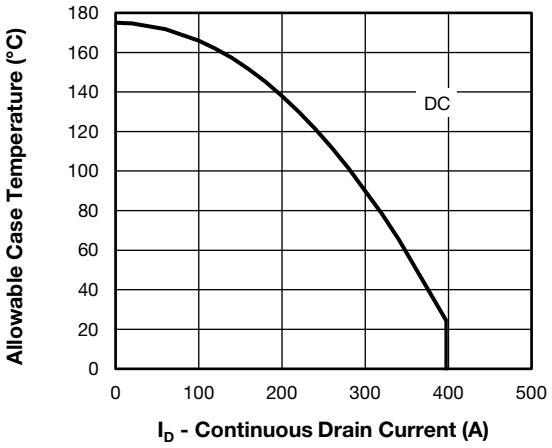

Fig. 1 - Maximum Continuous Drain Current vs. Case Temperature

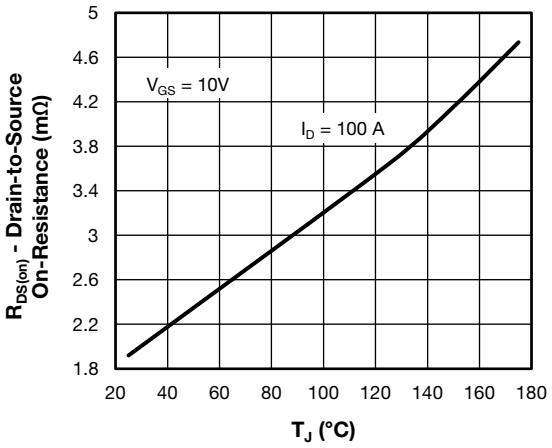

Fig. 4 - Typical Drain-to-Source On-Resistance vs. Temperature

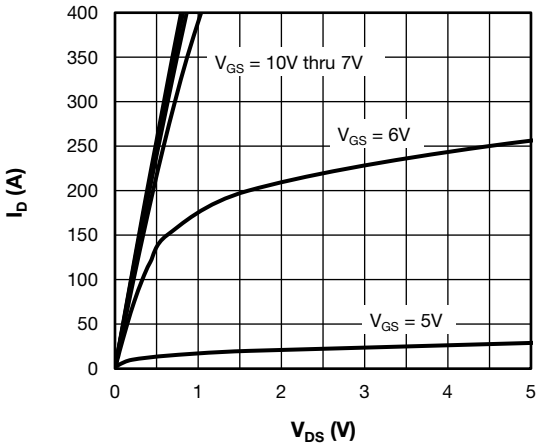

Fig. 2 - Typical Drain to Source Current Output Characteristics at T_J = 25 °C

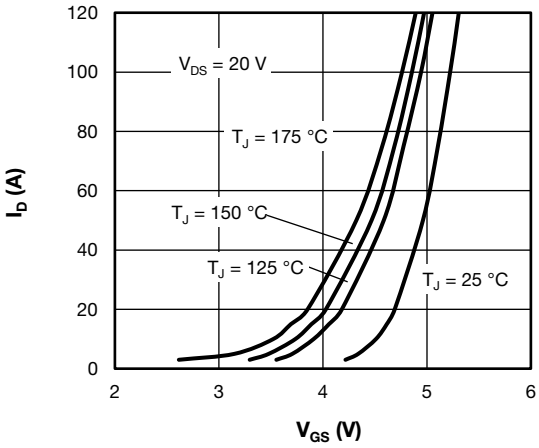

Fig. 5 - Typical Transfer Characteristics

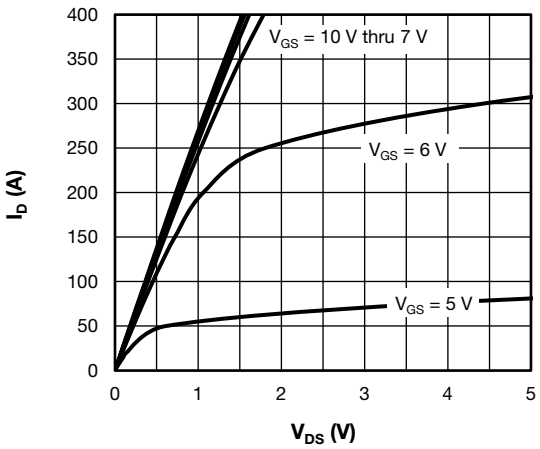

Fig. 3 - Typical Drain to Source Current Output Characteristics at T_J = 125 °C

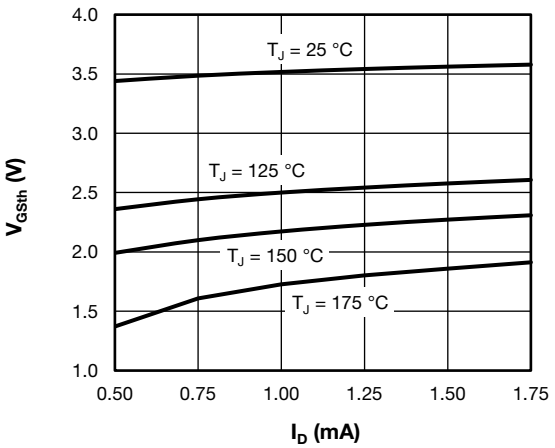

Fig. 6 - Typical Gate Threshold Voltage Characteristics

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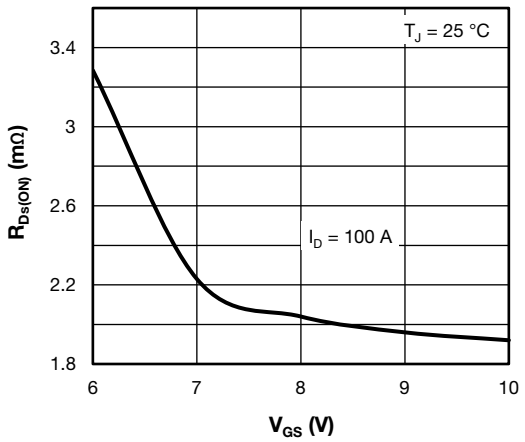

Fig. 7 - Typical Drain - State Resistance vs. Gate to Source Voltage

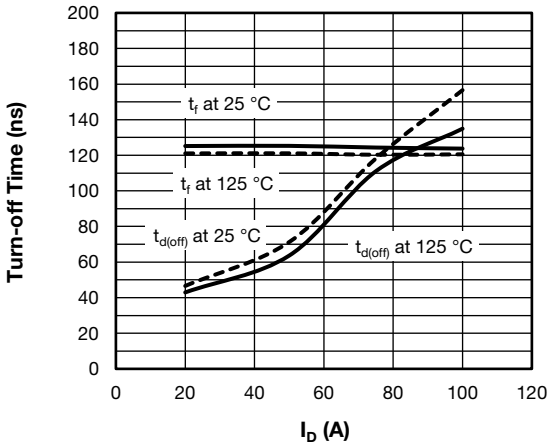

Fig. 10 - Typical Turn-off Switching Time vs. I_D

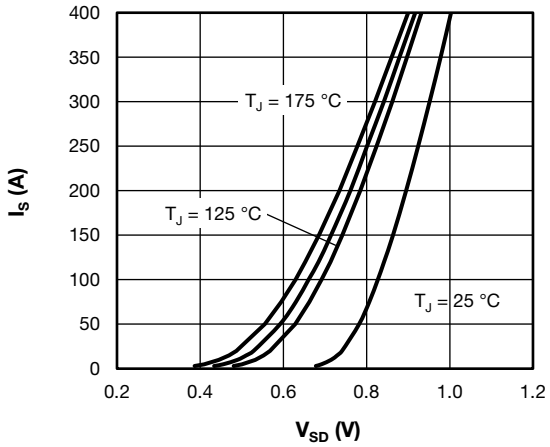

Fig. 8 - Typical Body Diode Source-to-Drain Current Characteristics

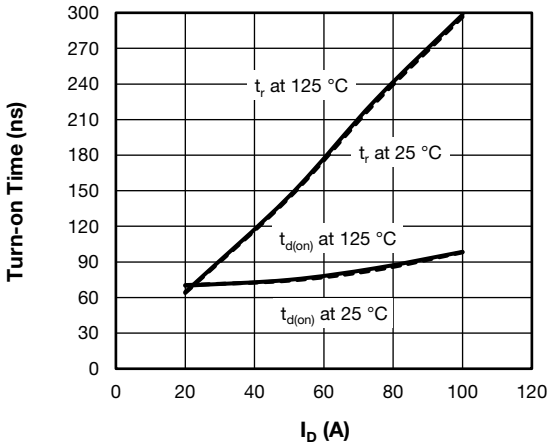

Fig. 11 - Typical Turn-on Switching Time vs. I_D

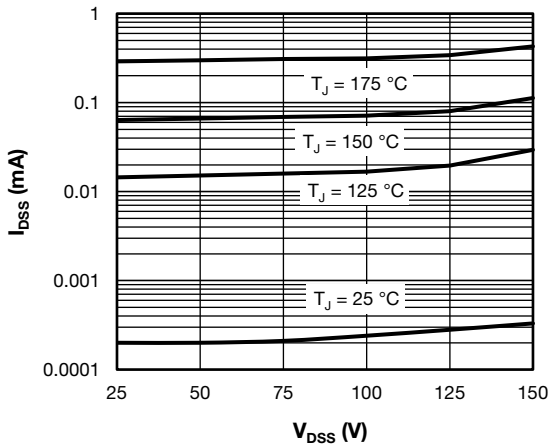

Fig. 9 - Typical Zero Gate Voltage Drain Current

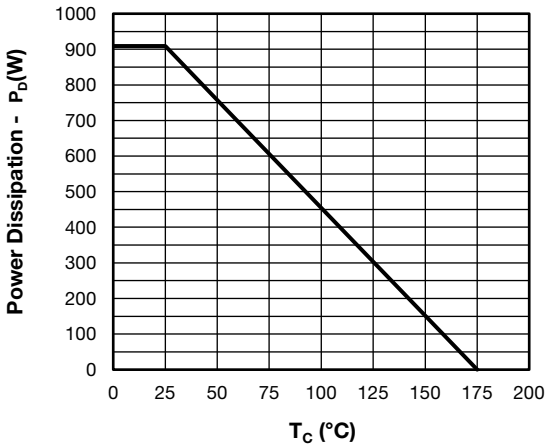

Fig. 12 - Power Dissipation Curve

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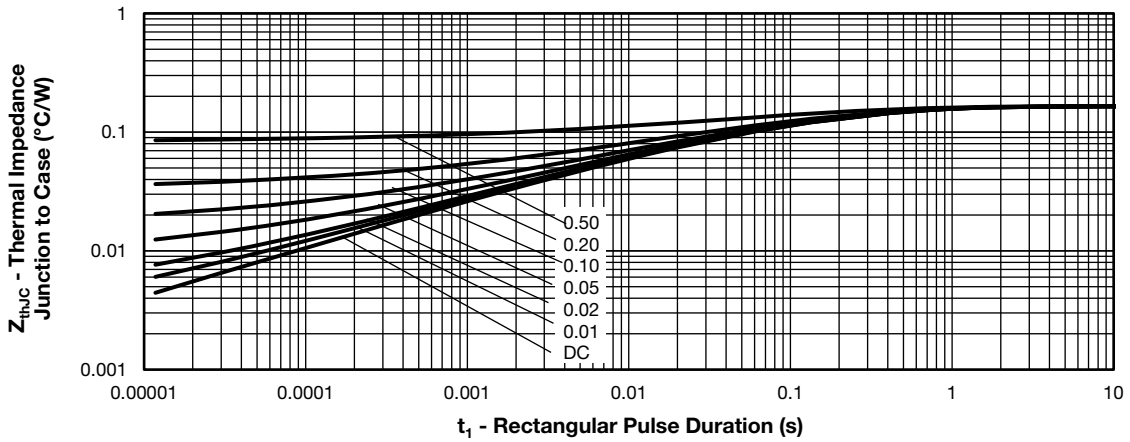

Fig. 13 - Maximum Thermal Impedance Junction-to-Case Characteristics

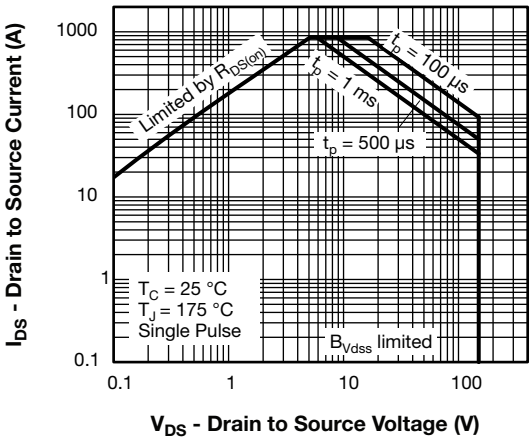

Fig. 14 - Safe Operating Area

ORDERING INFORMATION TABLE

Device code

VS-	F	C	420	S	A	15
1	2	3	4	5	6	7

1	-	Vishay Semiconductors product
2	-	MOSFET module
3	-	MOSFET die generation
4	-	Current rating (420 = 420 A)
5	-	Circuit configuration (S = single switch)
6	-	Package indicator (SOT-227)
7	-	Voltage rating (15 = 150 V)

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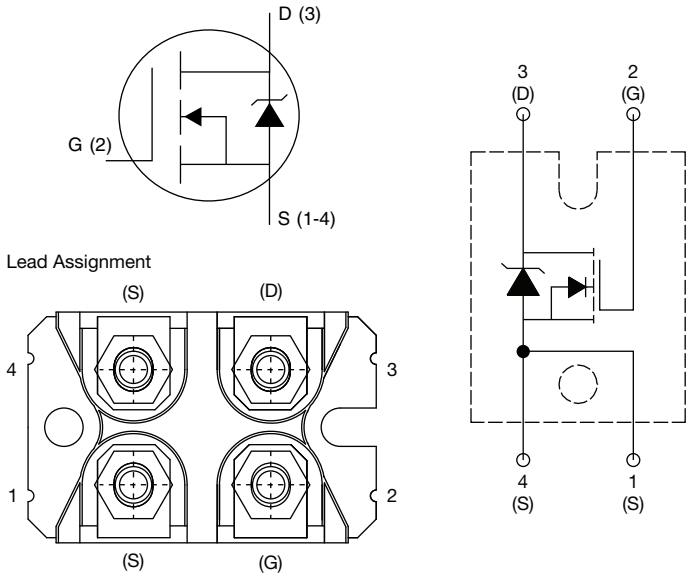
CIRCUIT CONFIGURATION		
CIRCUIT	**CIRCUIT CONFIGURATION CODE**	**CIRCUIT DRAWING**
Single switch	S	

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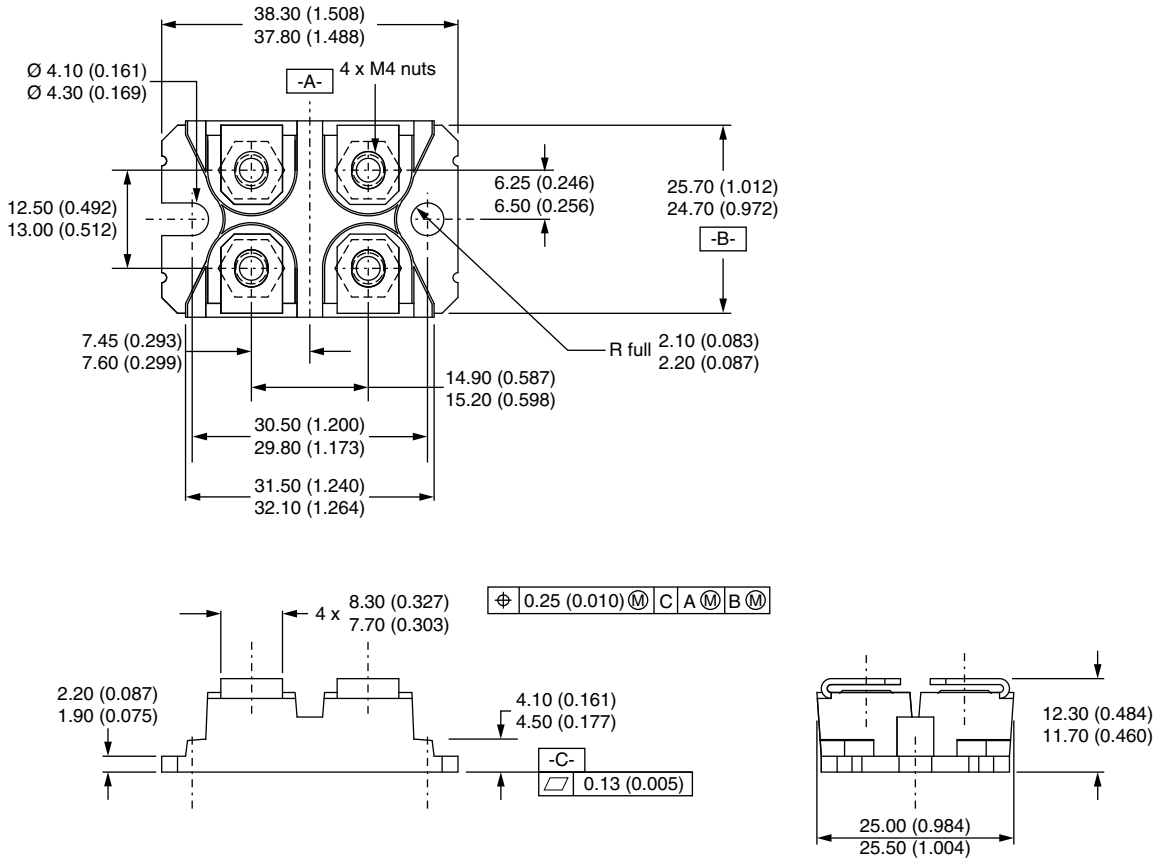
DIMENSIONS in millimeters



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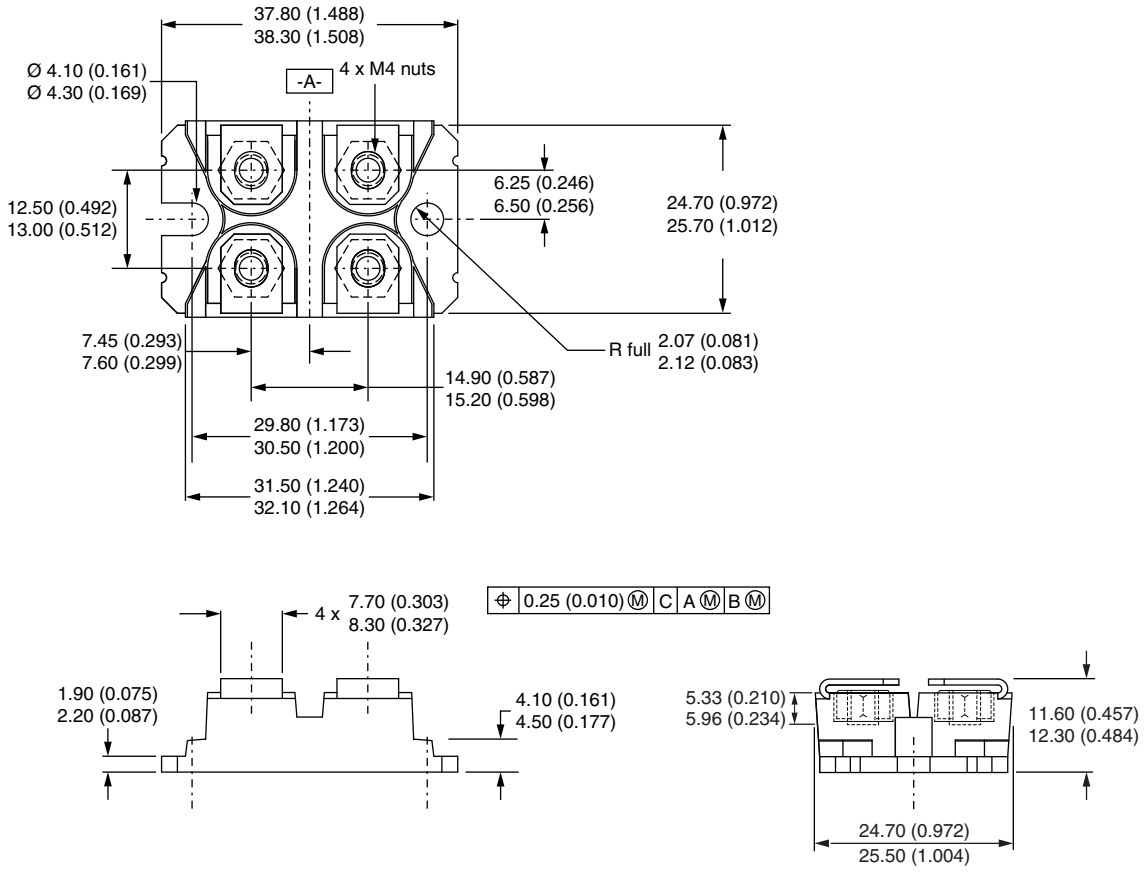
SOT-227 Generation 2

DIMENSIONS in millimeters (inches)



Note

- Controlling dimension: millimeter

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